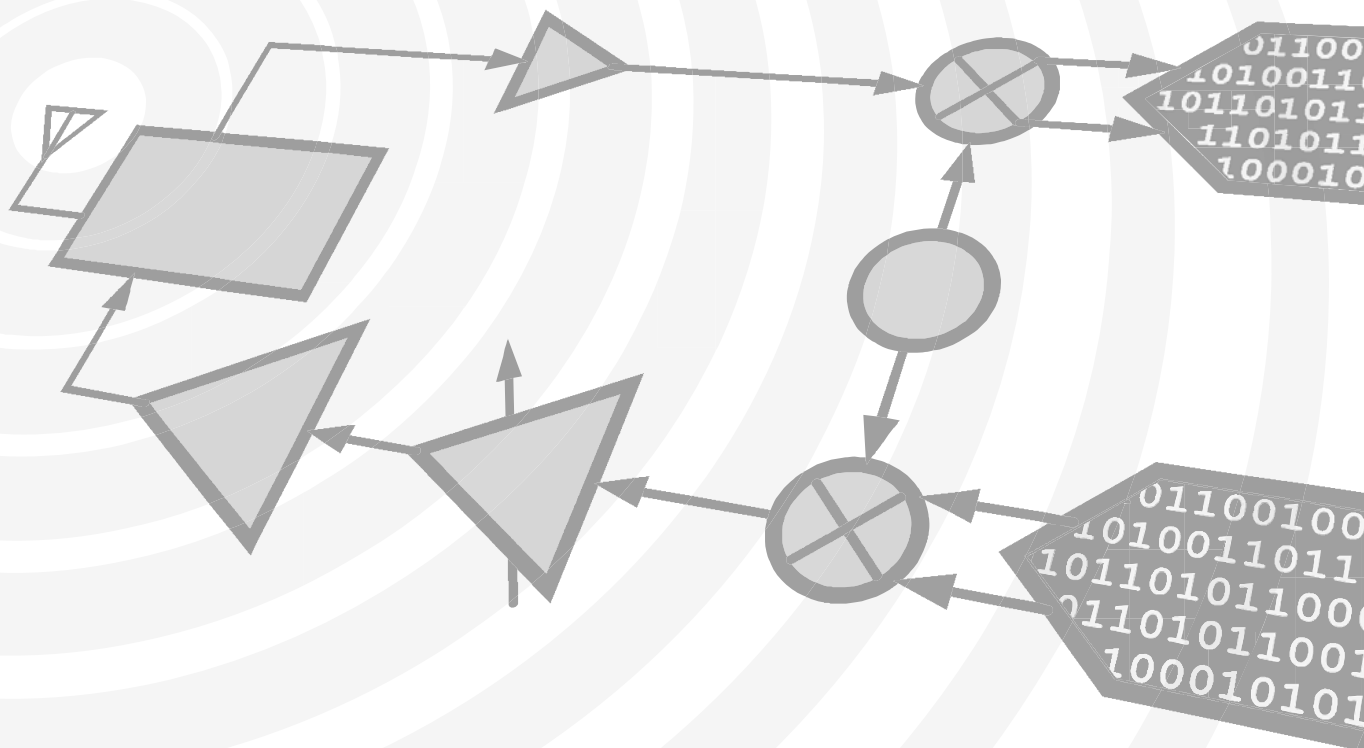




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MICROWAVE CORPORATION v03.1206



HMC491LP3 / 491LP3E

GaAs MMIC LOW NOISE AMPLIFIER w/ BYPASS MODE, 3.4 - 3.8 GHz

Typical Applications

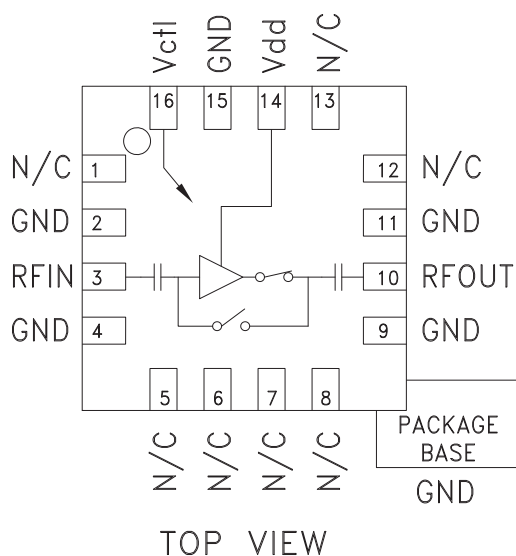
The HMC491LP3 / HMC491LP3E is ideal for:

- Wireless Local Loop (WLL)
- Fixed Wireless Access
- Microwave & VSAT Radios

Features

Gain: 16 dB
 Noise Figure: 2 dB
 Single Supply: +3V @ 9 mA
 Integrated Bypass Mode
 50 Ohm Matched Input/Output
 3 x 3 x 1 mm QFN SMT Package

Functional Diagram



General Description

The HMC491LP3 & HMC491LP3E are versatile, integrated, Low Noise Amplifiers (LNA) featuring a bypass mode intended for 3.4 to 3.8 GHz Fixed Wireless & WLL applications. The amplifier provides 16 dB of gain, 2 dB noise figure and +3 dBm input IP3 while requiring only 9 mA from a +3V supply. Using a single control line, the LNA can be switched into a low loss 2.2 dB bypass mode reducing the current consumption to 20 μ A. A low cost, leadless 3x3 mm QFN surface mount package (LP3) houses the amplifier. No external RF matching components are required.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = +3\text{V}$

Parameter	LNA Mode			LNA Mode			Bypass Mode			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range	3.4 - 3.6			3.6 - 3.8			3.4 - 3.8			GHz
Gain	14.5	17		13	15.5		-2.8	-2.3		dB
Gain Variation Over Temperature		0.012	0.02		0.012	0.02		0.004	0.008	dB / $^\circ\text{C}$
Noise Figure		2.2	2.7		2.0	2.5		--	--	dB
Input Return Loss		12			17			18		dB
Output Return Loss		9			7			11		dB
Reverse Isolation		34			33			--		dB
Input or Output Power for 1dB Compression (P1dB)*	3	6		4	7		25	28		dBm
Input Third Order Intercept (IP3) (-20 dBm Input Power per tone, 1 MHz tone spacing)		1			3			11		dBm
Supply Current (I _{dd})		9			9			0.03		mA

* P1dB for LNA Mode is referenced to RFOUT while P1dB for Bypass Mode is referenced to RFIN.



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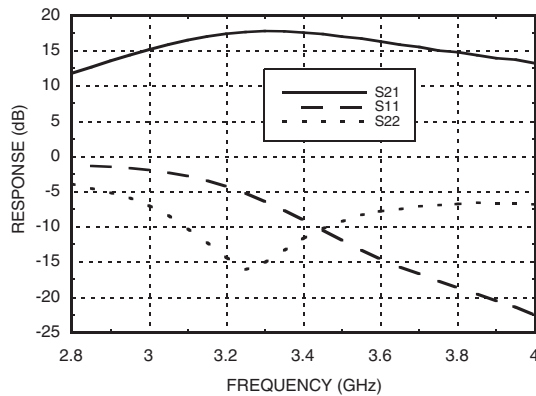
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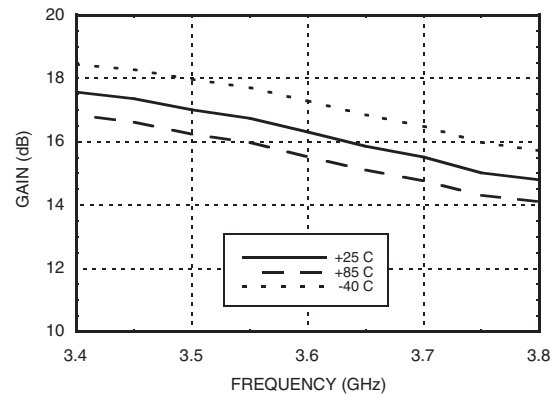
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LOW NOISE AMPLIFIERS - SMT

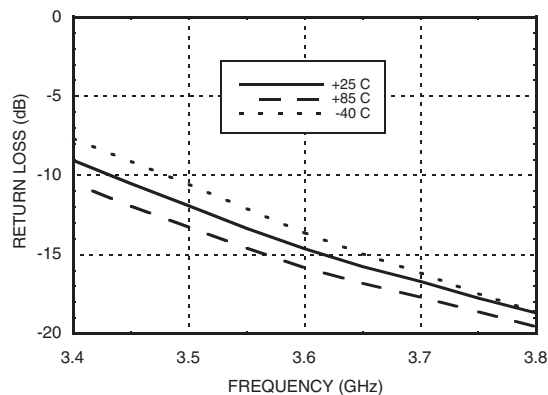
LNA Mode Broadband Gain & Return Loss



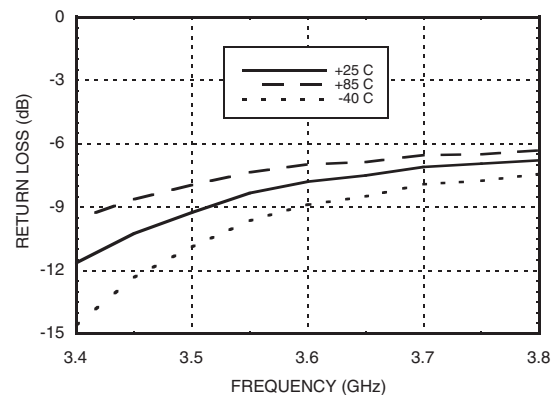
LNA Mode Gain vs. Temperature



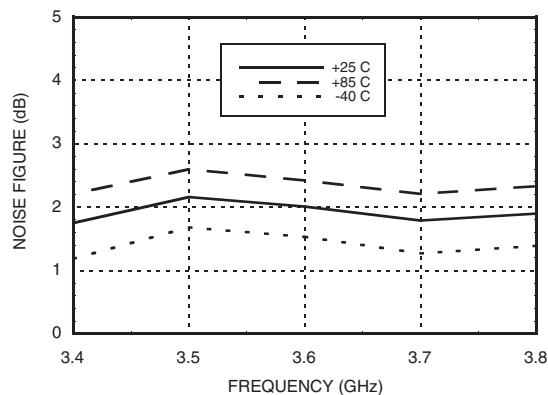
LNA Mode Input Return Loss vs. Temperature



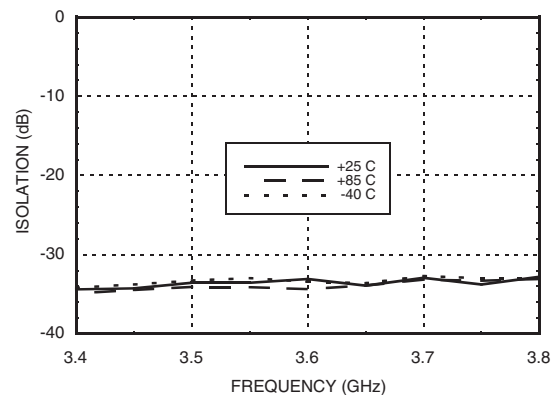
LNA Mode Output Return Loss vs. Temperature



LNA Mode Noise Figure vs. Temperature



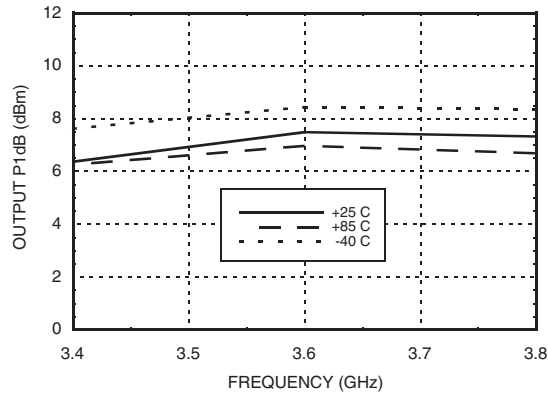
LNA Mode Reverse Isolation vs. Temperature



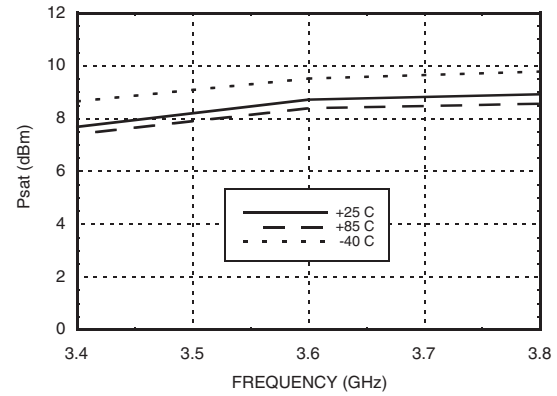
HMC491LP3 / 491LP3E

GaAs MMIC LOW NOISE AMPLIFIER w/ BYPASS MODE, 3.4 - 3.8 GHz

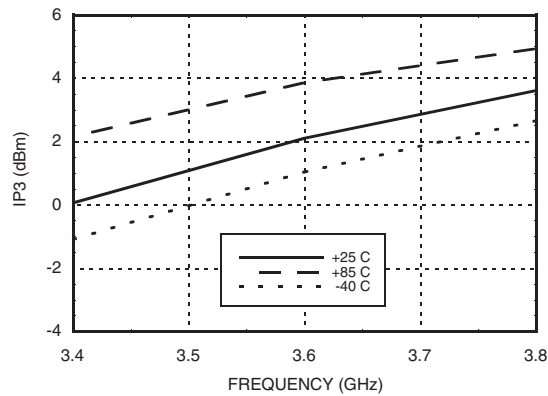
LNA Mode Output P1dB vs. Temperature



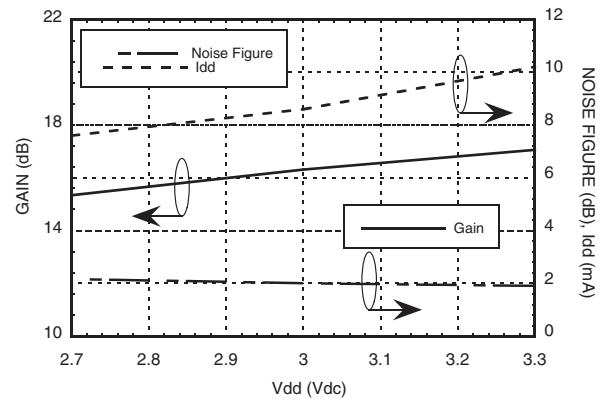
LNA Mode P_{sat} vs. Temperature



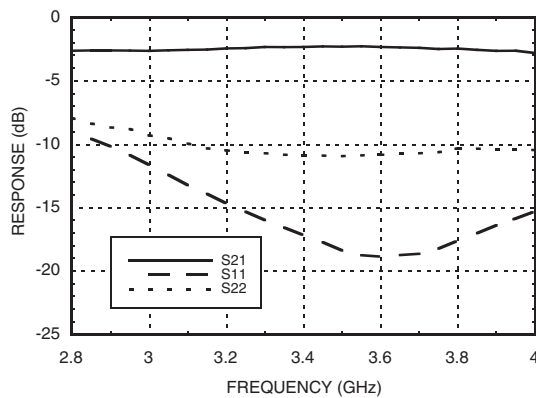
LNA Mode Input IP₃ vs. Temperature



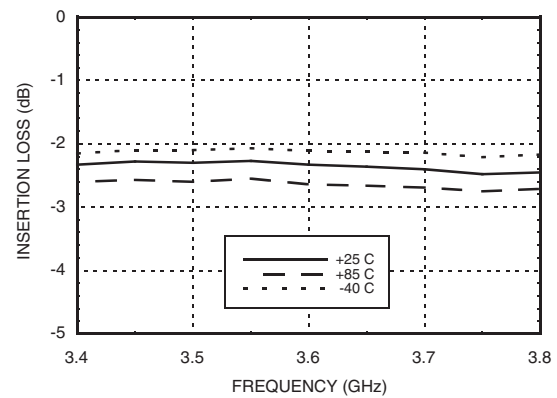
LNA Mode Gain, Noise Figure & Supply Current vs. Supply Voltage @ 3.6 GHz



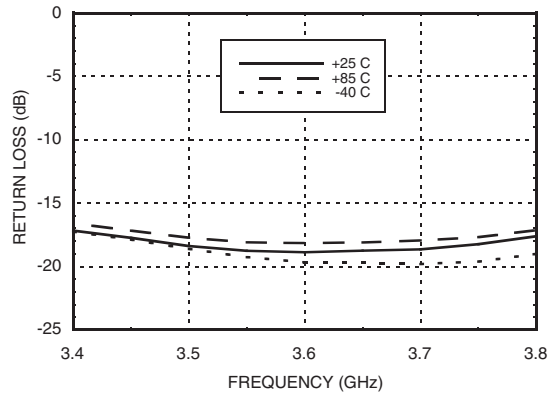
Bypass Mode Broadband Insertion Loss & Return Loss



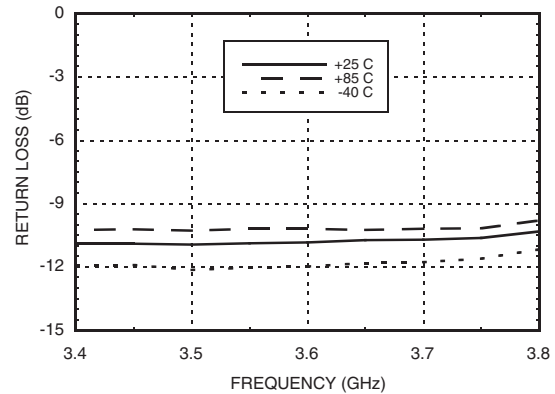
Bypass Mode Insertion Loss vs. Temperature



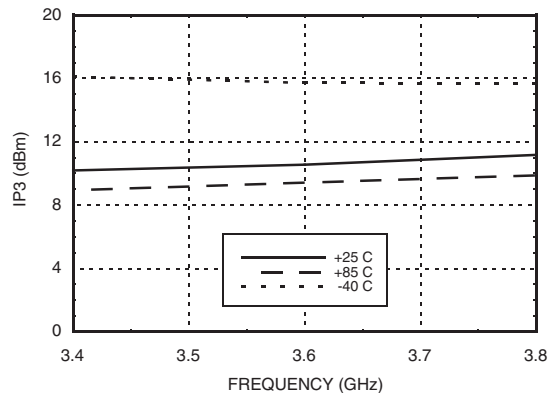
Bypass Mode Input Return Loss vs. Temperature



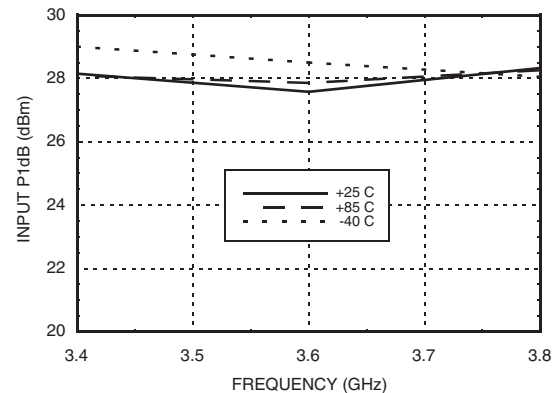
Bypass Mode Output Return Loss vs. Temperature



Bypass Mode Input IP3 vs. Temperature



Bypass Mode Input P1dB vs. Temperature



Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7.0 Vdc
RF Input Power (RFIN) LNA Mode	0 dBm
(Vdd = +3.0 Vdc) Bypass Mode	+30 dBm
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 1.8 mW/°C above 85 °C)	0.117 W
Thermal Resistance (channel to ground paddle)	556 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd

Vdd (Vdc)	I _{dd} (mA)
+2.7	7.6
+3.0	9.0
+3.3	10.2

Truth Table

LNA Mode	V _{ctl} = V _{dd} @ 1.6 mA
Bypass Mode	V _{ctl} = 0Vdc @ -13 µA
V _{dd} = +3V ±10%	



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS



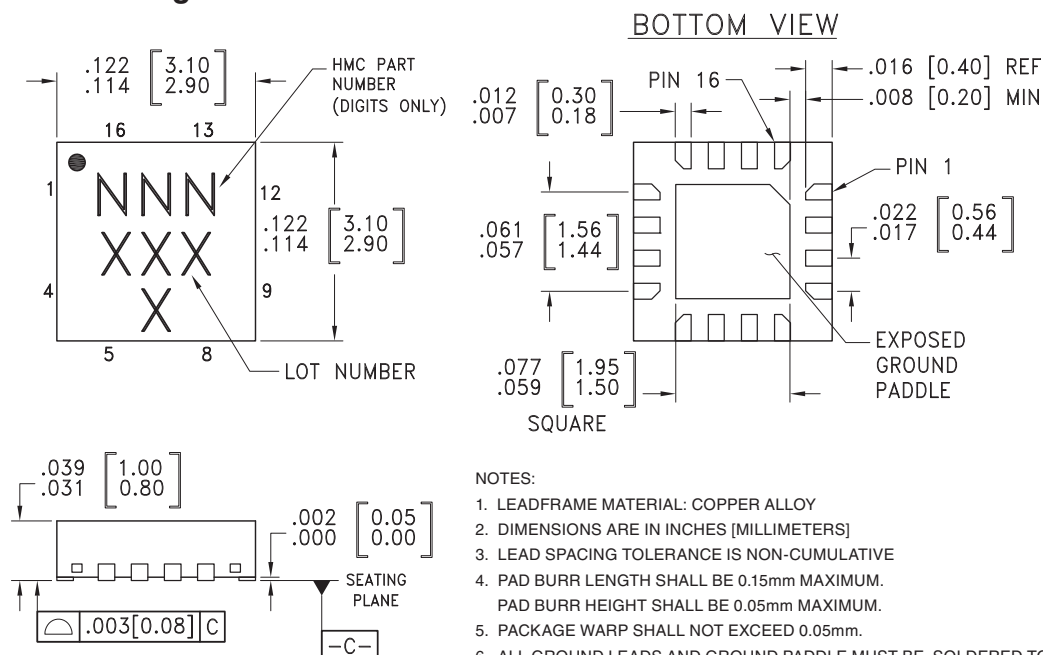
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Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC491LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	491 XXXX
HMC491LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	491 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

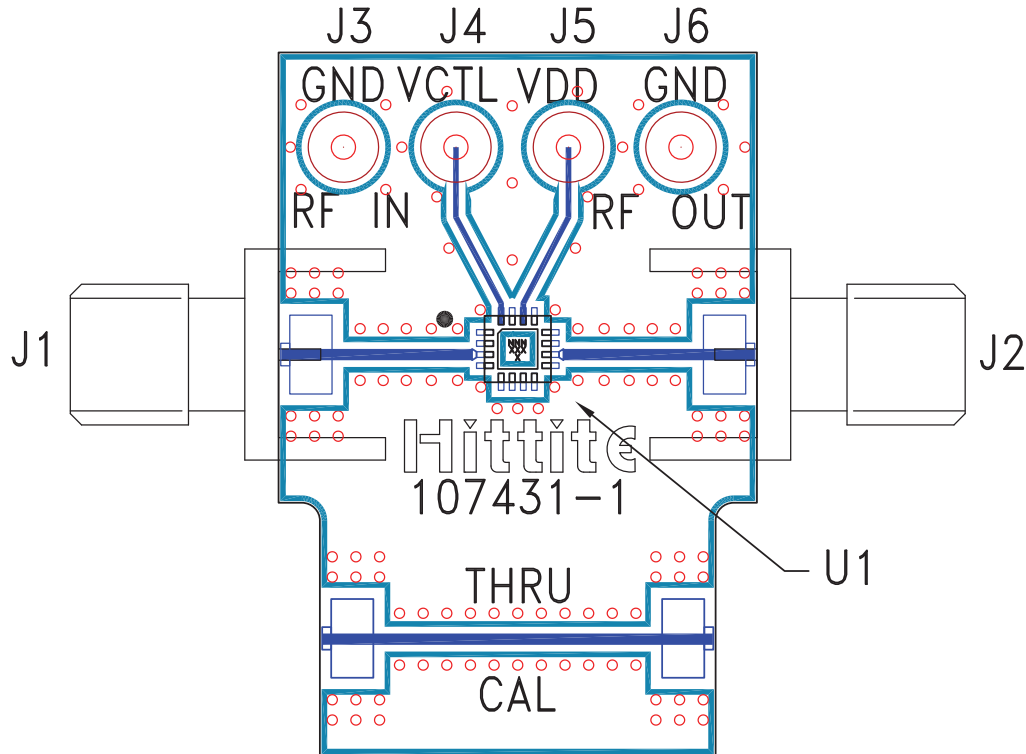
[3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5 - 8, 12, 13	N/C	No connection necessary. These pins may be connected to RF/DC ground.	
2, 4, 9, 11, 15	GND	These pins must be connected to RF/DC ground.	GND
3	RF IN	This pin is AC coupled and matched to 50 Ohms.	RFIN
10	RF OUT	This pin is AC coupled and matched to 50 Ohms.	RFOUT
14	Vdd	Power supply voltage.	Vdd
16	Vctl	Control voltage. Vctl= Vdd for LNA mode. Vctl= 0V for bypass mode.	Vctl

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

Evaluation PCB



List of Materials for Evaluation PCB 107174 ^[1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J6	DC Pin
U1	HMC491LP3 / HMC491LP3E Amplifier
PCB ^[2]	107431 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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